Spin-Hall and spin-diagonal conductivity in the presence of Rashba and Dresselhaus spin-orbit coupling

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We investigate the spin-current linear response conductivity tensor to an electric field in a paramagnetic two dimensional electron gas with both Rashba and Dresselhaus spin-orbit coupling in the weak scattering regime. In the usual case where both spin-orbit-split bands are occupied, we find that the spin-Hall conductivity depends only on the sign of the difference in magnitude of the Rashba and Dresselhaus coupling strengths except within a narrow window where both coupling strengths are equal. We also find a new effect in which a spin current is generated in the direction of the driving field whenever the Dresselhaus spin-orbit coupling is nonzero. We discuss experimental implications of this finding taking into account the finite mobility and typical parameters of current samples and possible experimental set ups for its detection.

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The manipulation of spin by electrical means in semiconducting environments has generated a lot of recent theoretical and experimental research aimed to develop useful spintonic devices and novel physical concepts [1], many focusing on effects that generate spin-polarized current [2]. Given the success of ferromagnetic metal based spintronic devices [3] which have revolutionized the information storage industry, the possibility of doping, gating, and heterojunction formation in seminconducting spintronic devices makes their possibilities that much wider. However, the practical implementation of semiconducting spintronics is awaiting the resolution of effective injection of spin-polarized carriers [4] from ferromagnetic metals combined with long spin lifetimes [5], or roomtemperature semiconductor ferromagnetism [6]. The recent discovery of the intrinsic spin-Hall effect by Murakami et al [7] in p-doped semiconductors and by Sinova et al [8] in Rashba spin-orbit coupled two dimensional electron gases (2EDGs) offers new avenues in spintronics research and transport phenomena which may meet the first challenge.

The intrinsic spin-Hall effect consist of a dissipationless spin-current generated perpendicular to the driving electric field in the weak-scattering limit where spin-orbit coupling is strong. This effect contrasts with the extrinsic spin-Hall effect recently revived by Hirsch [9] and Zhang [10] and first studied by Dyakonov and Perel [11], where spin-orbit dependent scattering from impurities can generate a Hall spin-current but will vanish in the weak scattering limit, where the intrinsic effect dominates. The intrinsic spin-Hall effect predicted by Murakami et al [7, 12] and Sinova et al [8, 13] has generated interest within the theoretical community [14, 15], supporting the need for a strong experimental effort in detecting such an effect. In the Rashba spin-orbit coupled 2DEGs it was shown that the intrinsic spin-Hall conductivity has a universal value $e/8\pi$ in the case of both spin-split subbands being occupied [8, 16]. Motivated by recent experiments

[17, 18] which have demonstrated the ability to tune the magnitude of the Rashba and Dresselhaus spin-orbit coupling strength directly and by the fact that when both coupling strengths are equal the quasiparticles are effectively spin-orbit decoupled [19] and the intrinsic spin-Hall effect should vanish, we extend our prior studies to include 2DEGs with both Rashba and Dresselhaus spinorbit coupling. We find that the spin Hall conductivity remains universal in the weak scattering limit except for a small window where the spin-orbit coupling strengths are equal and changes sign when the difference of the spin-orbit coupling strenghts change sign. We also find a novel effect in which a spin-polarized current is generated in the direction of the driving electric field whenever the Dresselhaus spin-orbit coupling is nonzero which should have important consequences if observed.

The Hamiltonian which we consider contains the spinorbit coupling interaction form for a two-dimensional electron gas [20]

$$H_{so} = \lambda (\hat{\sigma}_x p_y - \hat{\sigma}_y p_x) + \beta (\hat{\sigma}_x p_x - \hat{\sigma}_y p_y), \qquad (1)$$

where the first term is the Bychkov-Rashba term due to the lack of inversion symmetry of the trapping well [21] and the second is the linear Dresselhaus term due to the lack of inversion symmetry in bulk semiconductors [22]. Hence the full particle Hamiltonian can be written as

$$H = \left(\frac{\hat{p}^2}{2m^*} - \mu\right)\sigma_0 + \alpha_{ik}\sigma_i p_k, \ \alpha_{ik} = \left(\begin{array}{cc}\beta & \lambda\\-\lambda & -\beta\end{array}\right) \ (2)$$

This Hamiltonian has a simple spectra given by

$$\xi_{\pm}(\mathbf{k}) = \frac{\hbar^2 k^2}{2m^*} - \mu \pm k\sqrt{(\lambda^2 + \beta^2) + 2\lambda\beta sin(2\phi)} \quad (3)$$

where $\tan \phi = k_y/k_x$, μ is the chemical potential, and the corresponding eigenfunctions are given by

$$\psi_{\pm}(\mathbf{r}) = \frac{1}{\sqrt{2}} \begin{pmatrix} e^{i\theta_k/2} \\ \pm e^{-i\theta_k/2} \end{pmatrix} e^{i\mathbf{k}\cdot\mathbf{r}}$$
(4)

where

$$\tan \theta_k = \frac{\lambda k_x + \beta k_y}{\lambda k_y + \beta k_x}.$$
(5)

The Rashba coupling strength in a 2DEG can be modified by a gate field by up to 50% [17, 23] and therefore this system affords the study to the intricate interplay between both types of coupling directly whose ratio λ/β can vary between 1.5 and 2.5 typically [18]. Recent observations of a spin-galvaic effect [18, 24] and a spin-orbit coupling weak localization studies in these systems [17, 25, 26] illustrate the potential importance of these tunable interactions in semiconductor spintronics [27]. Indeed, this intricate interplay has generated several theoretical studies of their transport properties due to the anisotropies created in the Fermi surfaces for $\alpha \neq \beta$ [20, 28] and a new proposed spin-FET [19] in the regime where $\lambda = \beta$ motivated by the original proposal by Datta and Das [29].

In the Rashba coupled 2DEG ($\beta = 0$), Sinova *et al* [8] found that the dc z-component spin-current Hall response to a driving internal electric field, $j_s^z = \sigma_{xy}^{\text{spin}} E_y$, within the weak scattering limit has a universal value whenever the two Rashba split bands are occupied (the usual case), $\sigma_{xy}^{\text{spin}} = \frac{e}{8\pi}$, and vanishes linearly with the electron density when only one Rashba split band is occupied. This result was obtained both within the Kubo linear response formalism in the dc-weak scattering limit [8] and within an equivalent and more physically transparent multi-band wave-packet dynamics theory [13] generalizing the theory introduced by Qian et al [30] to account more rigorously for the consequences of the timedependent effective magnetic field that is experienced by the electron spins as they move through momentum space.

To address the interplay between the Rashba and Dresselhaus spin-orbit coupling and its consequence on the spin-current response to an applied electric field we use the linear response Kubo formalism in the weak scattering limit, where as usual it is assumed that the dc limit is taken with $\omega/\eta >> 1$ while both ω and η , the inverse of the quasiparticle lifetime induced by weak scattering, go

to zero [31]. We will address the effects of finite quasiparticle lifetime, i.e. finite mobility samples, within the Born approximation below similarly to references [32] and [15]. In this Kubo formalism approach, the intrinsic spin-Hall conductivity arises as a reactive term in the spin-current response to an electric field which has the form

$$\sigma_{\alpha y}^{\text{spin}} = e\hbar \sum_{n \neq n'} \int \frac{d\vec{k}}{(2\pi)^2} (f_{n',k} - f_{n,k}) \\ \times \frac{\text{Im}[\langle n'k | \hat{j}_{\text{spin }\alpha}^z | nk \rangle \langle nk | \hat{v}_y | n'k \rangle]}{(\xi_{nk} - \xi_{n'k})^2}$$
(6)

where $n, n' = \pm, \vec{j}_{\rm spin}^z = \frac{\hbar}{4} \{ \hat{\sigma}_z, \vec{v} \}, \vec{v} = \partial H(k) / \partial \hbar \vec{k}$, and $\alpha = x, y$ [27]. From the strong transport anisotropies induced by the change in Fermi surfaces whenever λ and β differ, it was expected that the universal spin-Hall conducitivity found in [8] in the weak scattering regime would be significantly modified. Inserting eigenvalues, Eq. 3, and eigenvectors, Eq. 4, above we obtain (for the experimentally relevant regime of both subbands being occupied):

$$\sigma_{xy}^{z} = \begin{cases} \frac{e}{8\pi} \text{ for } \lambda^{2} > \beta^{2} \\ 0 \text{ for } \lambda = \beta \\ -\frac{e}{8\pi} \text{ for } \lambda^{2} < \beta^{2} \end{cases}$$
(7)

$$\sigma_{yy}^{z} = \begin{cases} -\frac{e}{8\pi}\frac{\beta}{\lambda} \text{ for } \lambda^{2} > \beta^{2} \\ 0 \text{ for } \lambda = \beta \\ \frac{e}{8\pi}\frac{\lambda}{\beta} \text{ for } \lambda^{2} < \beta^{2} \end{cases}$$
(8)

These equations predict that the spin-Hall conductivity only depends on the sign of $\beta^2 - \lambda^2$, and that there is a diagonal (in the sense that it points along the driving field direction) reactive part of the spin-current whenever β is non-zero and $\beta \neq \lambda$. The sharpness and singularities of these results are simply an artifact of the $\eta \rightarrow 0$ limit which can be easily rectified by introducing a finite lifetime to the spin-orbit coupled quasiparticles induced by the weak scattering in the usual Born approximation approach [32, 33] given by

$$\sigma_{\alpha y}^{spin} = -\frac{e}{\omega} \int \frac{d\vec{k}d\epsilon}{(2\pi)^3} \sum_{nn'} \operatorname{Im}[\langle n'\vec{k}|\hat{j}_{spin\ \alpha}^z | n\vec{k}\rangle \langle n\vec{k}|\hat{v}_y | n'\vec{k}\rangle] f(\epsilon) \left[A_{n',\vec{k}}(\epsilon) \operatorname{Re}[G_{n,k}^{\operatorname{ret}}(\epsilon+\hbar\omega)] + A_{n,\vec{k}}(\epsilon) \operatorname{Re}[G_{n',k}^{\operatorname{adv}}(\epsilon-\hbar\omega)]\right], (9)$$

where $A_{n,\vec{k}}(\epsilon) = \eta/((\epsilon - \xi_{n\vec{k}})^2 + \eta^2/4)$ is the disorder broadened spectral function and $G_{n,k}^{\text{ret/adv}}(\hbar\omega) = 1/(\hbar\omega - \xi \pm i\eta/2)$ are the advanced and retarded quasiparticle Green's functions with finite lifetime $2\eta^{-1}/\hbar$ (here chosen

to be momentum independent for simplicity). The above expression can be evaluated numerically, however, we can make progress understanding qualitative the effect of finite quasiparticle lifetime by taking the further approximation that the spectral function is sharp enough to allow one to substitute it for a delta function. This simplification translates into adding a small complex value to the frequency in the frequency dependent response function from which the weak scattering dc limit expression, Eq. 6 was obtained. The expression that is obtained is identical to Eq. 6 but with the denominator replaced by $\eta^2 + (\xi_{n\vec{k}} + \xi_{n'\vec{k}})^2$. Anticipating already the typical experimental situation where the Fermi energy is only slightly modified from its non-spin-orbit coupled form, we obtain after some straightforward algebraic manipulation the expressions

and

$$\sigma_{yy}^{\text{spin}} = -\frac{e\left(\epsilon_{\beta} - \epsilon_{\lambda}\right)}{16\pi\sqrt{\epsilon_{\beta}\epsilon_{\lambda}}} \left(1 - \frac{\eta^2 + 8\epsilon_F(\epsilon_{\lambda} + \epsilon_{\beta})}{\sqrt{\eta^4 + 64\epsilon_F^2(\epsilon_{\beta} - \epsilon_{\lambda})^2 + 16\eta^2\epsilon_F(\epsilon_{\beta} + \epsilon_{\lambda})}}\right) \tag{11}$$

where ϵ_F is the Fermi energy, and $\epsilon_{\lambda} = m\lambda^2/\hbar^2$ and $\epsilon_{\beta} = m\beta^2/\hbar^2$ are the spin-orbit coupling characteristic energy scales for the Rashba and Dresselhauss mechanisms defined in the same way as Ref. [15], and $\epsilon_F >> \epsilon_{\lambda}, \epsilon_{\beta}$ is assumed. In the limit of $\eta \to 0$ one recovers Eqs. 10 and 11, although near the $\alpha = \beta$ point we see that one limit goes smoothly but fairly rapidly to the next in the scale of η as illustrated in Fig. 1. This analysis illustrates our earlier statement [8] indicating that, unlike the universal Hall conductivity value on a 2DEG quantum Hall plateau, the universality of the intrinsic spin Hall effect does not extend to the disorder domain. And, as expected [8] the spin Hall conductivity $\sigma_{xy}^{\rm spin}$ and the spin diagonal conductivity $\sigma_{yy}^{\rm spin}$ is slightly suppressed for $\epsilon_F, |\epsilon_{\lambda} - \epsilon_{\beta}| > \eta$

$$\sigma_{xy}^{\text{spin}} = \frac{e}{8\pi} \left(1 - \frac{\eta^2(\epsilon_\lambda + \epsilon_\beta)}{8\epsilon_F(\epsilon_\lambda - \epsilon_\beta)^2} \right)$$
(12)

$$\sigma_{yy}^{\text{spin}} = \frac{e}{8\pi} \sqrt{\frac{\epsilon_{\beta}}{\epsilon_{\lambda}}} \left(1 - \frac{\eta^2 \epsilon_{\lambda}}{4\epsilon_F (\epsilon_{\lambda} - \epsilon_{\beta})^2} \right)$$
(13)

for $\epsilon_{\lambda} > \epsilon_{\beta}$, and for $\epsilon_{\lambda} < \epsilon_{\beta}$ the equations have opposite sign and we must switch ϵ_{β} and ϵ_{λ} in Eq. 13. We note that Eq. 12 is in agreement with Ref. [15] for $\beta = 0$. The strong disorder limit of Eqs. 10 and 11 the spin conductivity tensor goes as $\epsilon_F \epsilon_{\lambda/\beta}/\eta^2$ but in this case one must still assume $\epsilon_F/\eta >> 1$ (a basic justification of the above approximation) and therefore $\epsilon_{\lambda/\beta}/\eta \ll 1$ is the condition for such effects to vanish. In such a limit we expect that the extrinsic contribution from skew scattering proposed by Hirsch may dominate since at this stage scattering from impurities may be more important than the intrinsic spin-orbit coupling subband splitting. We also note that the specific coefficients in the above expression proportional to η^2 will change since the full expression 9 which takes into account the broadening present in the occupation number must be used in a quantitative analysis.

 $\sigma_{xy}^{\text{spin}} = \frac{e}{8\pi} \frac{\epsilon_F(\epsilon_\lambda - \epsilon_\beta)}{\sqrt{\epsilon_F^2(\epsilon_\lambda - \epsilon_\beta)^2 + \eta^2 \epsilon_F(\epsilon_\beta + \epsilon_\lambda)/4 + \eta^4/64}}$

In current 2DEGs high quality samples [17, 18, 23, 34] the typical carrier concentrations range from 5×10^{11} to 10^{12} cm⁻², the λ, β range is $1 - 5 \times 10^{-11}$ eVm, and the mobilities range is 1 - 50 m²/Vs. In terms of the effective mass ratio m^*/m_e the energy scales defined above are given by

$$\epsilon_F \approx 0.24 \frac{n_{2D} [10^{11} \mathrm{cm}^{-2}]}{m^*/m_e},$$
 (14)

$$\epsilon_{\lambda/\beta} \approx 1.31 \frac{m^*}{m_e} (\lambda/\beta [10^{-11} eVm])^2$$
 (15)

$$\eta \approx \frac{0.116}{\mu[m/Vs](m^*/m_e)},$$
 (16)

with μ being in this case the mobility of the sample. For the typical $m^*/m_e = 0.05$ in InAs based heterostructures gives a range of $\epsilon_F = 20-50$ meV, $\epsilon_{\lambda/\beta} = 0.07-1.6$ meV, and $\eta = 0.05-2.3meV$. This indicates that current samples (although not all) are already within the regime where these effects should be observable and the weak scattering regime applicable. Outside this weak scattering regime we note that will be a further contribution to σ_{sH} , like that envisaged by Hirsch [9], but in the limit emphasized here (weak scattering limit) it will not dominate in the high-mobility 2DEG's [35].

It is also important to note that the intrinsic character of our spin Hall effect, compared to the extrinsic character of the effect discussed by Hirsch [9], is analogous to the intrinsic contribution to the anomalous Hall effect recently emphasize in various studies [30, 32, 36, 37, 38], proposed to be the main contribution to the anomalous Hall effect in some ferromagnets and strongly polarized paramagnets. In both cases scattering contributions to the Hall conductivities can become important if skew scattering [39] is present, especially when the overall electron scattering rate is small and the steady state distri-

(10)

bution function of the current-carrying state is strongly disturbed compared to the equilibrium one. In the case of (III,Mn)V ferromagnetic semiconductors for example, the intrinsic theory of the anomalous Hall effect accounts rather convincingly for experimental observations [36].

Besides the several approaches already proposed to measure the spin-Hall effect [7, 8, 12, 37], the tunability of both the Rashba and Dresselhaus coupling parameters [17, 18] and the non-zero diagonal spin-current generated in the presence of a linear Dresselhaus term offers new possibilities. We propose a bottom gate sample coupled with non-contact probes such as spatially resolved Kerr effect measuremnts, ferromagnetic STM, or Scanning Hall probe microscope. Having four non-contact local probe observations (two for Hall and two for diagonal conductivity) on the edges of the sample as a function of gate voltage which varies the Rashba and Dresselhaus coupling [17, 18] simultaneous acquisition of transverse and diagonal spin currents without the usual spurious geometrical effects present in typical transport measurements.

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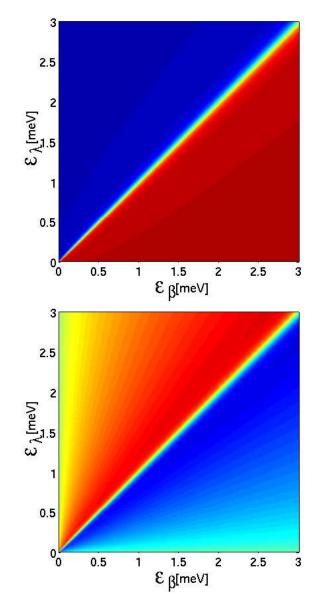


FIG. 1: Color plot of $\sigma_{xy}^{\rm spin}$ (upper figure) and $\sigma_{yy}^{\rm spin}$ vs. $\epsilon_{\beta} = m^* \beta^2 / \hbar^2$ and $\epsilon_{\lambda} = m^* \beta^2 / \hbar^2$ with Fermi energy $\epsilon_F = 50$ meV, $\eta = 0.63 meV$, and $m^* / m_e = 0.05$. The color scale is bright red $= e/8\pi$ and dark blue $= -e/8\pi$.

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